

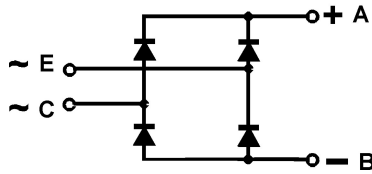
Single Phase Rectifier Bridges Slim Version

PSBS 112

$I_{dAVM} = 84 \text{ A}$
 $V_{RRM} = 800-1800 \text{ V}$

Preliminary Data Sheet

V_{RSM} V	V_{RRM} V	Type
800	800	PSBS 112/08
1200	1200	PSBS 112/12
1400	1400	PSBS 112/14
1600	1600	PSBS 112/16
1800	1800	PSBS 112/18



Symbol	Test Conditions	Maximum Ratings
I_{dAVM}	$T_C = 100^\circ\text{C}$, module	84 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	1200 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	1300 A
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	1000 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	1100 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	7200 A ² s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	7200 A ² s
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	5000 A ² s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	5000 A ² s
T_{VJ}		-40 ... + 150 °C
T_{VJM}		150 °C
T_{stg}		-40 ... + 125 °C
V_{ISOL}	50/60 HZ, RMS $t = 1 \text{ min}$	2500 V ~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000 V ~
M_d	Mounting torque (M6)	5 Nm
	Terminal connection torque (M6)	5 Nm
Weight	typ.	225 g

Features

- Low profile (overall height: 17 mm)
- Package with screw terminals
- Isolation voltage 3000 V~
- Planar glasspassivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL release applied, RoHS conform

Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

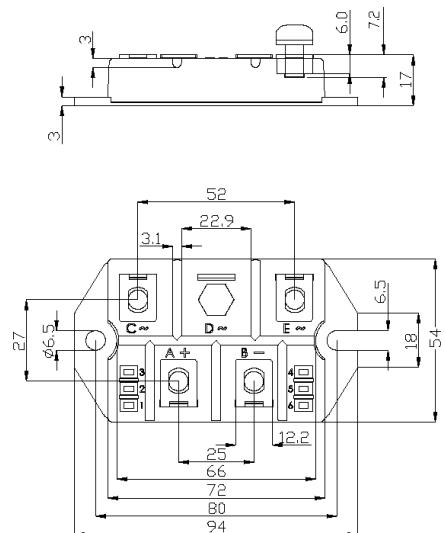
- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability

Package, style and outline

Dimensions in mm (1mm = 0.0394")

Symbol	Test Conditions	Characteristic Value
I_R	$V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$	$\leq 0.3 \text{ mA}$
	$V_R = V_{RRM}$ $T_{VJ} = T_{VJM}$	$\leq 5.0 \text{ mA}$
V_F	$I_F = 150 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$	$\leq 1.7 \text{ V}$
V_{TO}	For power-loss calculations only	0.8 V
r_T	$T_{VJ} = T_{VJM}$	5 mΩ
R_{thJC}	per diode; DC current	0.85 K/W
	per module	0.2125 K/W
R_{thJK}	per diode; DC current	1.05 K/W
	per module	0.263 K/W
d_s	Creeping distance on surface	10.0 mm
d_A	Creeping distance in air	9.4 mm
a	Max. allowable acceleration	50 m/s ²

Max. allowed screw-in depth: 7.2 mm



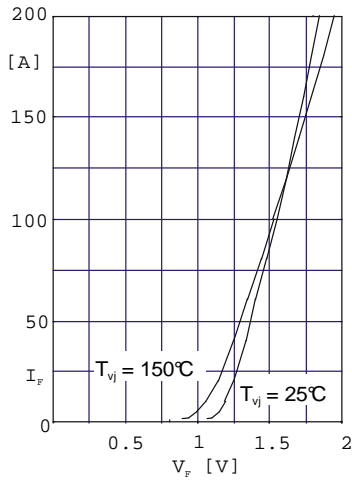


Fig. 1 Forward current versus voltage drop per diode

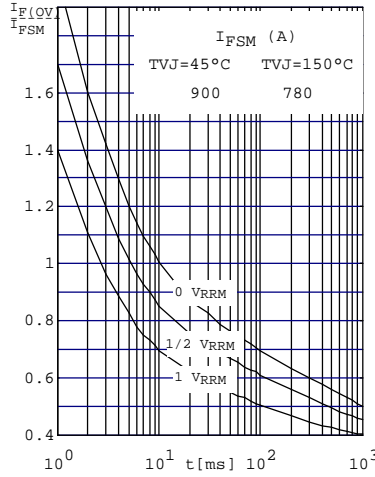


Fig. 2 Surge overload current per diode I_{FSM} : Crest value. t : duration

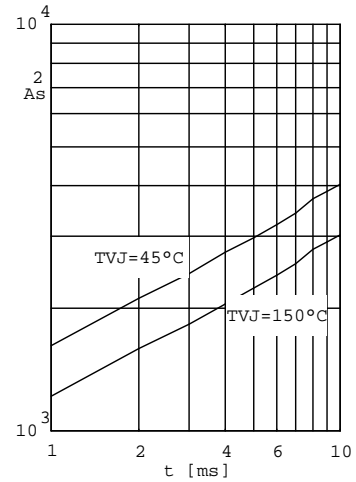


Fig. 3 $\int i^2 dt$ versus time (1-10ms) per diode

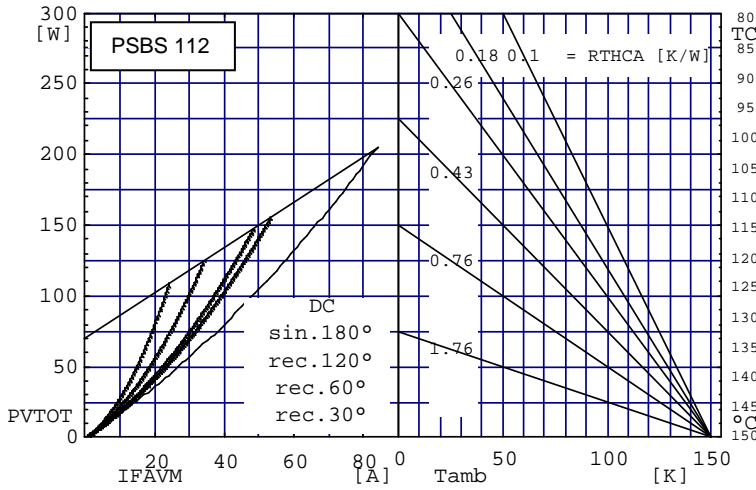


Fig. 4 Power dissipation versus direct output current and ambient temperature

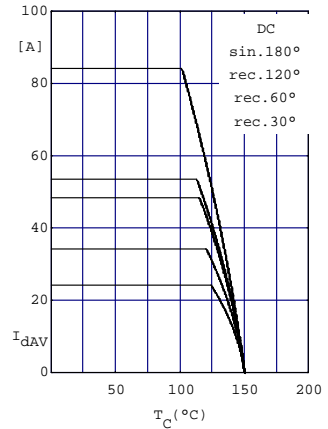


Fig. 5 Maximum forward current at case temperature

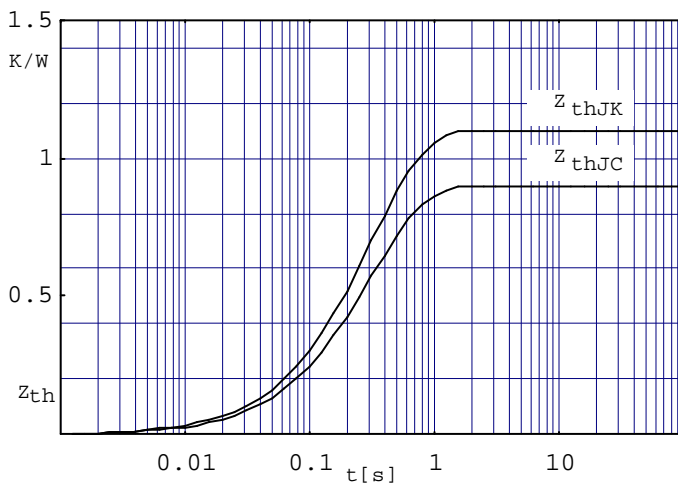


Fig. 6 Transient thermal impedance per diode